# Silicon P Channel Power MOS FET High Speed Power Switching

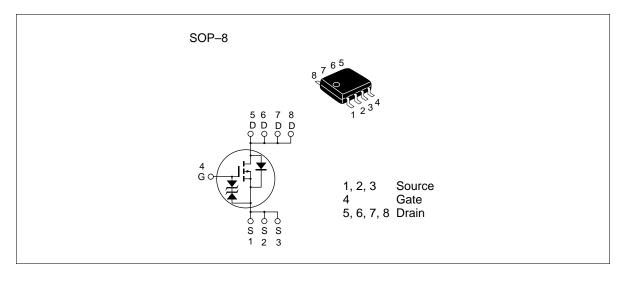
# **HITACHI**

ADE-208-475 D (Z) 5th. Edition February 1999

#### **Features**

- Low on-resistance
- Capable of 2.5 V gate drive
- Low drive current
- High density mounting

#### **Outline**





### **Absolute Maximum Ratings** ( $Ta = 25^{\circ}C$ )

Item	Symbol	Ratings	Unit
Drain to source voltage	$V_{\scriptscriptstyle DSS}$	- 20	V
Gate to source voltage	$V_{GSS}$	± 10	V
Drain current	I <sub>D</sub>	- 5.5	A
Drain peak current	Note1 D(pulse)	<b>- 44</b>	A
Body-drain diode reverse drain current	I <sub>DR</sub>	- 5.5	A
Channel dissipation	Pch Note2	2.5	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Note: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1 %

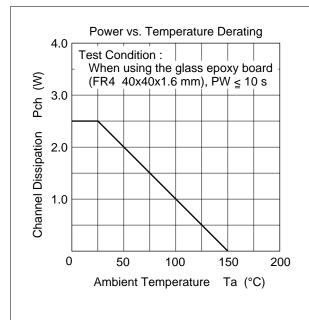
2. When using the glass epoxy board (FR4 40 x 40 x 1.6 mm), PW $\leq$  10s

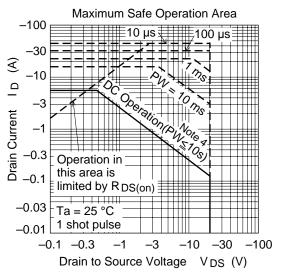
#### **Electrical Characteristics** ( $Ta = 25^{\circ}C$ )

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	- 20	_	_	V	$I_D = -10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	± 10	_	_	V	$I_{G} = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	± 10	μΑ	$V_{GS} = \pm 8 \text{ V}, V_{DS} = 0$
Zero gate voltege drain current	I <sub>DSS</sub>	_	_	<b>- 10</b>	μΑ	$V_{DS} = -20 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	- 0.5	_	- 1.5	V	$V_{DS} = -10 \text{ V}, I_{D} = -1 \text{ mA}$
Static drain to source on state	R <sub>DS(on)</sub>	_	0.048	0.060	Ω	$I_D = -3 \text{ A}, V_{GS} = -4 \text{ V}^{\text{Note3}}$
resistance	R <sub>DS(on)</sub>	_	0.065	0.085	Ω	$I_D = -3 \text{ A}, V_{GS} = -2.5 \text{ V}^{\text{Note3}}$
Forward transfer admittance	y <sub>fs</sub>	6	9.5	_	S	$I_D = -3 \text{ A}, V_{DS} = -10 \text{ V}^{\text{Note3}}$
Input capacitance	Ciss	_	1200	_	pF	V <sub>DS</sub> = - 10 V
Output capacitance	Coss	_	630	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	200	_	pF	f = 1MHz
Turn-on delay time	t <sub>d(on)</sub>	_	20	_	ns	$V_{GS} = -4 \text{ V}, I_{D} = -3 \text{ A}$
Rise time	t <sub>r</sub>	_	120	_	ns	$V_{DD} \cong -10 \text{ V}$
Turn-off delay time	t <sub>d(off)</sub>	_	175	_	ns	_
Fall time	t <sub>f</sub>	_	140	_	ns	_
Body-drain diode forward voltage	$V_{DF}$	_	- 0.9	- 1.4	V	$IF = -5.5 \text{ A}, V_{GS} = 0^{\text{Note3}}$
Body-drain diode reverse recovery time	t <sub>rr</sub>	_	65	_	ns	IF = $-5.5$ A, $V_{GS} = 0$ diF/ dt = 20 A/ $\mu$ s

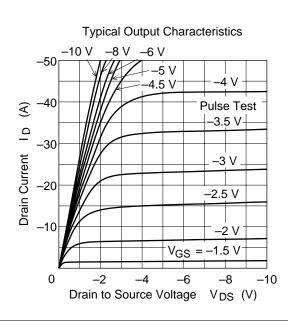
Note: 3. Pulse test

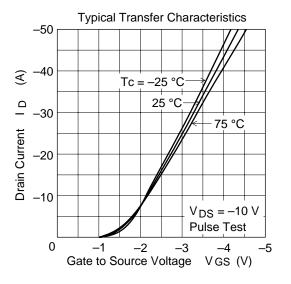
#### **Main Characteristics**

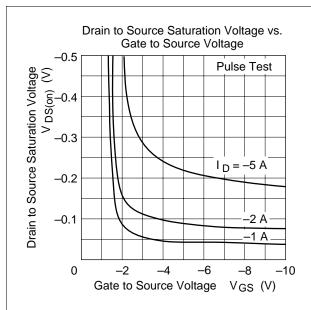


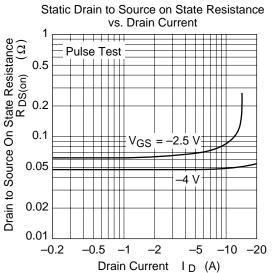


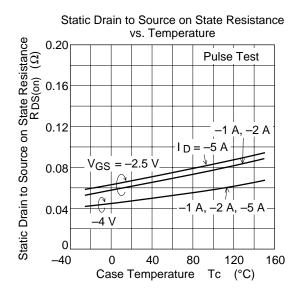
Note 4:
When using the glass epoxy board (FR4 40 x 40 x 1.6 mm)

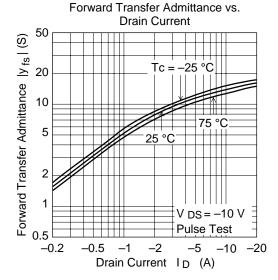


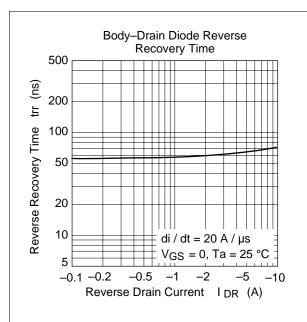


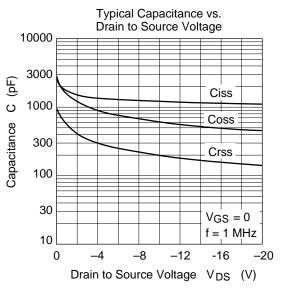


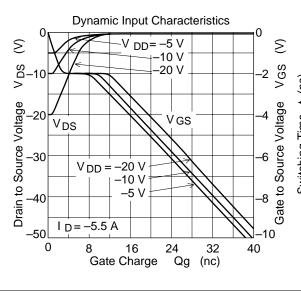


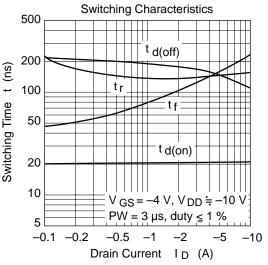


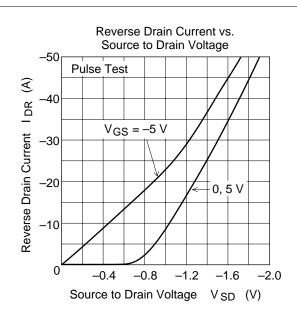


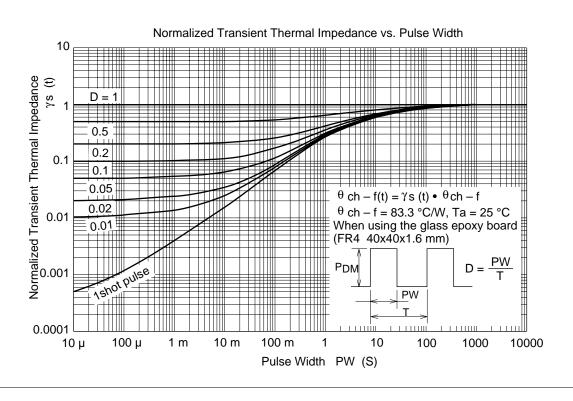


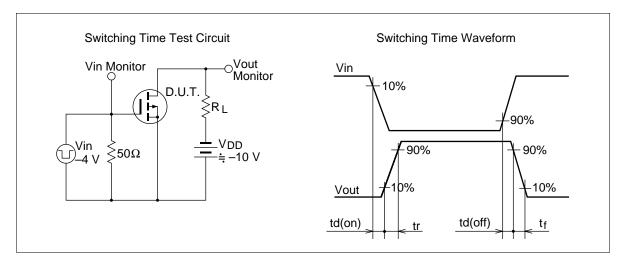






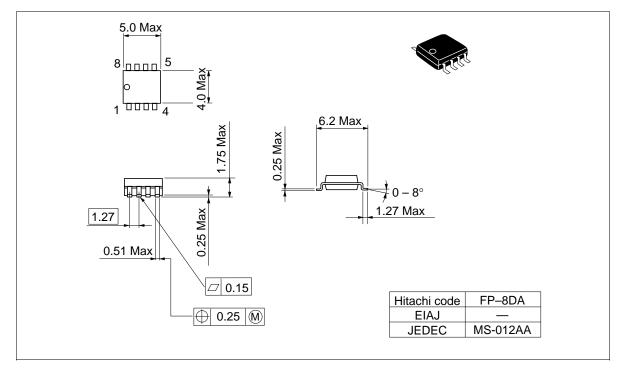






#### **Package Dimensions**

Unit: mm



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